VN2406L

Preferred Device

Small Signal MOSFET 200 mAmps, 240 Volts

N-Channel TO-92

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	240	Vdc
Drain-Gate Voltage	VDGR	240	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	± 20 ± 40	Vdc Vpk
Continuous Drain Current	ΙD	200	mAdc
Pulsed Drain Current	IDM	500	mAdc
Power Dissipation @ T _C = 25°C Derate above 25°C	PD	350 2.8	mW mW/°C
Operating and Storage Temperature	T _J , T _{stg}	1	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	312.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16" from case for 10 seconds	TL	300	°C

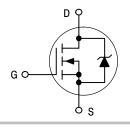


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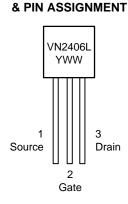
http://onsemi.com

200 mAMPS 240 VOLTS RDS(on) = 6 Ω

N-Channel







Y = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping	
VN2406L	TO-92	1000 Units/Box	
VN2406LZL1	TO-92	2000 Ammo Pack	

Preferred devices are recommended choices for future use and best overall value.

VN2406L

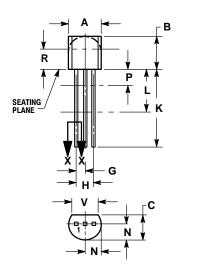
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

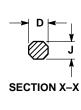
	Symbol	Min	Max	Unit	
STATIC CHARACTERISTICS		,		•	•
Drain–Source Breakdown Voltage (V _{GS} = 0, I _D = 100 μA)		V _(BR) DSS	240	-	Vdc
Zero Gate Voltage Drain Current (V _{DS} = 120 Vdc, V _{GS} = 0) (V _{DS} = 120 Vdc, V _{GS} = 0, T _A	IDSS	_ _	10 500	μAdc	
Gate- Body Leakage (V _{DS} = 0, V _{GS} = ±15 V)	I _{GSS}	-	±100	nAdc	
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.0 mA)	VGS(th)	0.8	2.0	Vdc	
On–State Drain Current (Note 1) (VGS = 10 V, VDS \geq 2.0 VDS(0	I _{D(on)}	1.0	-	Adc	
Drain–Source On Resistance (Note 1) (V _{GS} = 2.5 V, I _D = 0.1 A) (V _{GS} = 10 V, I _D = 0.5 A)		r _{DS(on)}	- -	10 6.0	Ω
Forward Transconductance (Note 1) (V _{DS} = 10 V, I _D = 0.5 A)		9fs	300	-	mS
DYNAMIC CHARACTERISTIC	cs	-			
Input Capacitance		C _{iss}	_	125	pF
Output Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{oss}	-	50	pF
Reverse Transfer Capacitance	,	C _{rss}	_	20	pF
SWITCHING CHARACTERIS	TICS			•	
Turn-On Time	$(V_{DD} = 60 \text{ Vdc}, I_D = 0.4 \text{ A},$ $R_L = 150 \Omega, R_G = 25 \Omega)$	t(on)	_	8.0	ns
		t _(r)	-	8.0	ns
Turn-Off Time		t(off)	-	23	ns
		t _(f)	-	34	ns

^{1.} Pulse Test; Pulse Width < 300 μ s, Duty Cycle \leq 2.0%.

PACKAGE DIMENSIONS

TO-92 CASE 29-11 **ISSUE AL**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
v	0 135		3 43		

STYLE 22:
PIN 1. SOURCE
2. GATE
3. DRAIN

VN2406L

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